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650 V Power SiC Merged PIN Schottky Diode, 6 A



LINKS TO ADDITIONAL RESOURCES







PRIMARY CHARACTERISTICS				
I _{F(AV)}	6 A			
V_{R}	650 V			
V _F at I _F at 150 °C	1.70 V			
T _J max.	175 °C			
I _R at V _R at 175 °C	4.4 μA			
Q _C (V _R = 400 V)	17 nC			
Package	2L TO-220AC			
Circuit configuration	Single			

FEATURES

 Majority carrier diode using Schottky technology on SiC wide band gap material



Positive V_F temperature coefficient for easy paralleling

- Virtually no recovery tail and no switching losses
- Temperature invariant switching behavior
- 175 °C maximum operating junction temperature
- MPS structure for high ruggedness to forward current surge events
- Meets JESD 201 class 1A whisker test
- Solder bath temperature 275 °C maximum, 10 s per JESD 22-B106
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Wide band gap SiC based 650 V Schottky diode, designed for high performance and ruggedness.

Optimum choice for high speed hard switching and efficient operation over a wide temperature range, it is also recommended for all applications suffering from Silicon ultrafast recovery behavior.

Typical applications include AC/DC PFC and DC/DC ultra high frequency output rectification in FBPS and LLC converters.

MECHANICAL DATA

Case: 2L TO-220AC

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

Mounting torque: 10 in-lbs maximum

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C unless otherwise specified)					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V_{RRM}		650	V	
Average rectified forward current	I _{F(AV)}	T _C = 127 °C (DC)	6	Α	
DC blocking voltage	V_{DC}		650	V	
Repetitive peak surge current	I _{FRM}	T_C = 25 °C, f = 50 Hz, square wave, DC = 25 %	23		
Non-repetitive peak forward surge current	I _{FSM}	$T_C = 25$ °C, $t_p = 10$ ms, half sine wave	39	А	
		$T_C = 110 ^{\circ}\text{C}, t_p = 10 \text{ms}, \text{half sine wave}$	37		
Power dissipation	P _{tot} (1)	T _C = 25 °C	42	W	
		T _C = 110 °C	18		
I ² t value	∫i ² dt	T _C = 25 °C	8	A ² s	
		T _C = 110 °C	6.8		
Operating junction and storage temperatures	T _J ⁽²⁾ , T _{Stg}		-55 to +175	°C	

Notes

⁽¹⁾ Based on maximum Rth

 $^{^{(2)}}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$



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ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Forward voltage	V _F	I _F = 6 A	-	1.45	1.70		
		I _F = 6 A, T _J = 150 °C	-	1.70	2.10	V	
		I _F = 6 A, T _J = 175 °C	-	1.80	-		
Reverse leakage current	I _R	$V_R = V_R$ rated	-	-	35	μА	
		V _R = V _R rated, T _J = 150 °C	-	-	75		
		V _R = V _R rated, T _J = 175 °C	-	4.4	-		
Total capacitance	С	V _R = 1 V, f = 1 MHz	-	250	-	nΕ	
		V _R = 400 V, f = 1 MHz	-	27	-	pF	
Total capacitive charge	Q _C	V _R = 400 V, f = 1 MHz	-	17	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS (T _A = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction-to-case	R _{thJC}		-	2.55	3.6	°C/W
Marking device		C06ET07T				

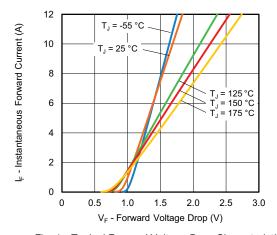


Fig. 1 - Typical Forward Voltage Drop Characteristics

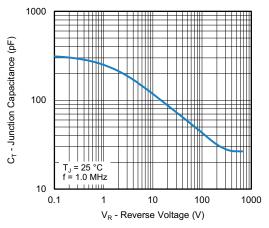


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

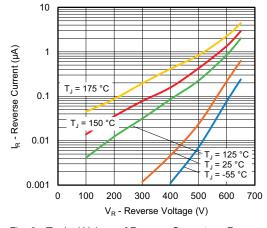


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

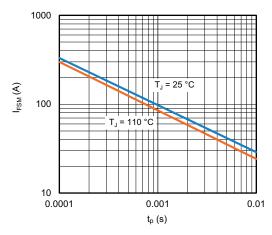


Fig. 4 - Non-Repetitive Peak Forward Surge Current vs. Pulse Duration (Square Wave)

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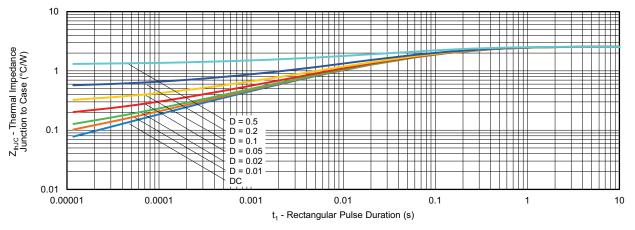


Fig. 5 - Typical Thermal Impedance Z_{thJC} Characteristics

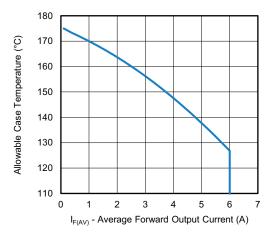


Fig. 6 - Maximum Allowable Case Temperature vs. Average Forward Current

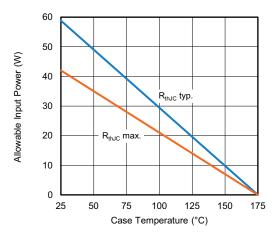


Fig. 7 - Forward Power Loss Characteristics

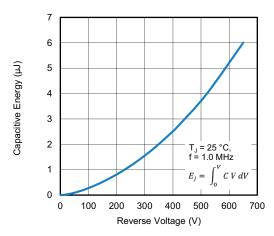


Fig. 8 - Typical Capacitive Energy vs. Reverse Voltage

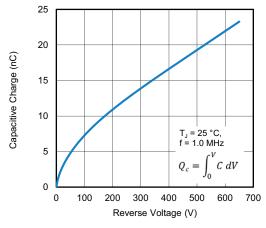


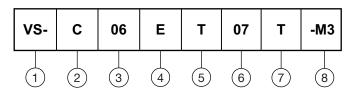
Fig. 9 - Typical Capacitive Charge vs. Reverse Voltage



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ORDERING INFORMATION TABLE

Device code



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2 - C = SiC diode

3 - Current rating (06 = 6 A)

E = single diodePackage TO-220

6 - Voltage rating: (07 = 650 V)

7 - T = true 2 pin

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION					
PREFERRED P/N	BASE QUANTITY	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-C06ET07T-M3	50/tube	1000	Antistatic plastic tubes		

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96069			
Part marking information	www.vishay.com/doc?95391			
SPICE model	www.vishay.com/doc?96830			



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